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CONTENTS

15 JULY 2000-II

RAPID COMMUNICATIONS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Enhancement and suppression of thermal emission by a three-dimensional photonic crystal R2243
Shawn-Yu Lin, J. G. Fleming, E. Chow, Jim Bur, K. K. Choi, and A. Goldberg
- Heavy photons at coupled-cavity waveguide band edges in a three-dimensional photonic crystal R2247
Mehmet Bayindir and E. Ozbay

Semiconductors I: bulk

- Oxygen configurations in silica R2251
James R. Chelikowsky, D. J. Chadi, and N. Binggeli
- Localization length and impurity dielectric susceptibility in the critical regime of the metal-insulator transition in
homogeneously doped *p*-type Ge R2255
Michio Watanabe, Kohei M. Itoh, Youiti Ootuka, and Eugene E. Haller
- Group V acceptors in CdTe: *Ab initio* calculation of lattice relaxation and the electric-field gradient R2259
Stephan Lany, Peter Blaha, Joachim Hamann, Volker Ostheimer, Herbert Wolf, and Thomas Wichert

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Exploiting exciton-exciton interactions in semiconductor quantum dots for quantum-information processing R2263
Filippo Troiani, Ulrich Hohenester, and Elisa Molinari
- NMR-based nanostructure switch for quantum logic R2267
John H. Reina, Luis Quiroga, and Neil F. Johnson
- Evidence for a shear horizontal resonance in supported thin films R2271
X. Zhang, M. H. Manghnani, and A. G. Every
- L*-to-*X* crossover in the conduction-band minimum of Ge quantum dots R2275
F. A. Reboredo and Alex Zunger
- Evidence of polariton stimulation in semiconductor microcavities R2279
F. Boeuf, R. André, R. Romestain, Le Si Dang, E. Péronne, J. F. Lampin, D. Hulin, and A. Alexandrou
- Relaxation bottleneck and its suppression in semiconductor microcavities R2283
A. I. Tartakovskii, M. Emam-Ismaïl, R. M. Stevenson, M. S. Skolnick, V. N. Astratov, D. M. Whittaker,
J. J. Baumberg, and J. S. Roberts

Surface physics, low-dimensional systems, and related topics

- Gold clusters (Au_N , $2 \leq N \leq 10$) and their anions R2287
Hannu Häkkinen and Uzi Landman
- Electronic and structural properties of carbon nanohorns R2291
Savas Berber, Young-Kyun Kwon, and David Tománek



Interaction of CO with the reconstructed Au(111) surface near atmospheric pressures	R2295
P. Steadman, K. Peters, H. Isern, J. Alvarez, and S. Ferrer	
Real-time study of nucleation, growth, and ripening during Fe/Fe(100) homoepitaxy using ion scattering	R2299
R. Pfandzelter, T. Igel, and H. Winter	
Extended energy range of Ag quantum-well states in Ag(111)/Au(111)/W(110)	R2303
A. M. Shikin, D. V. Vyalikh, Yu. S. Dedkov, G. V. Prudnikova, V. K. Adamchuk, E. Weschke, and G. Kaindl	
Local electronic properties of single-wall nanotube circuits measured by conducting-tip AFM	R2307
M. Freitag, M. Radosavljević, W. Clauss, and A. T. Johnson	

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Transferable relativistic Dirac-Slater pseudopotentials	2311
Ilya Grinberg, Nicholas J. Ramer, and Andrew M. Rappe	
Temperature and filling dependence of the superconducting π phase in the Penson-Kolb-Hubbard model	2315
Fabrizio Dolcini and Arianna Montorsi	
Dimensional crossover of the exchange-correlation density functional	2321
P. García-González	
Minimum principles and level splitting in quantum Monte Carlo excitation energies: Application to diamond	2330
M. D. Towler, Randolph Q. Hood, and R. J. Needs	
Theory of orbital excitation and resonant inelastic x-ray scattering in manganites	2338
Sumio Ishihara and Sadamichi Maekawa	
Excitonic order at strong coupling: Pseudospin, doping, and ferromagnetism	2346
Leon Balents	
Strong-coupling approach for strongly correlated electron systems	2358
Andrij M. Shvaika	
Effect of Hund coupling on one-dimensional Luttinger liquids	2372
H. C. Lee and S.-R. Eric Yang	
Quantum phase transitions and collapse of the Mott gap in the $d=1+\epsilon$ dimensional Hubbard model with $2k_F$ umklapp scattering	2377
Jun-ichiro Kishine	
Quantum oscillations and phase diagram of α -(BEDT-TTF) ₂ TlHg(SCN) ₄	2388
Cyril Proust, Alain Audouard, Alexei Kovalev, David Vignolles, Mark Kartsovnik, Luc Brossard, and Natalia Kushch	
Mo cluster formation in the intercalation compound LiMoS ₂	2397
X. Rocquefelte, F. Boîte, P. Gressier, G. Ouvrard, P. Blaha, and K. Schwarz	
Distribution function of the local density of states of a one-channel weakly disordered ring in an external magnetic field	2401
H. Feldmann, E. P. Nakhmedov, and R. Oppermann	
Cyclotron effective masses in layered metals	2416
Jaime Merino and Ross H. McKenzie	
Gap to transition-temperature ratio in density-wave ordering: A dynamical mean-field study	2424
Stefan Blawid and Andrew Millis	
Primary photoexcitations in oligophenylenevinylene thin films probed by femtosecond spectroscopy	2429
G. Cerulo, G. Lanzani, S. De Silvestri, H.-J. Egelhaaf, L. Lüer, and D. Oelkrug	
Theory of solid-state contributions to the x-ray elastic scattering amplitude	2437
A. L. Ankudinov and J. J. Rehr	

Elastic wave scattering by periodic structures of spherical objects: Theory and experiment	2446
Zhengyou Liu, C. T. Chan, Ping Sheng, A. L. Goertzen, and J. H. Page	
Transfer-matrix approach for modulated structures with defects	2458
T. Kostyrko	
Semiconductors I: bulk	
Electronic excitations in beryllium chalcogenides from the <i>ab initio</i> GW approach	2466
A. Fleszar and W. Hanke	
First-principles calculations of the thermodynamic and structural properties of strained $\text{In}_x\text{Ga}_{1-x}\text{N}$ and $\text{Al}_x\text{Ga}_{1-x}\text{N}$ alloys	2475
L. K. Teles, J. Furthmüller, L. M. R. Scolfaro, J. R. Leite, and F. Bechstedt	
Resonant states induced by shallow acceptors in uniaxially strained semiconductors	2486
M. A. Odnoblyudov, I. N. Yassievich, V. M. Chistyakov, and K. A. Chao	
Capacitance transient spectroscopy models of coupled trapping kinetics among multiple defect states: Application to the study of trapping kinetics of defects in heavy-ion-damaged silicon	2496
P. K. Giri and Y. N. Mohapatra	
Formation of polaron pairs and time-resolved photogeneration of free charge carriers in π -conjugated polymers	2505
Eugene Frankevich, Hisao Ishii, Yasushi Hamanaka, Takahiro Yokoyama, Akihiko Fuji, Sergey Li, Katsumi Yoshino, Arao Nakamura, and Kazuhiko Seki	
Correlation effects beyond Hartree-Fock theory and polarization dependence of four-wave mixing in bulk GaAs at high magnetic field	2516
N. A. Fromer, P. Kner, D. S. Chemla, R. Löwenich, and W. Schäfer	
Statistical Ga clusters and $A_1(\text{TO})$ gap mode in $\text{Al}_x\text{Ga}_{1-x}\text{N}$ alloys	2522
A. A. Klochikhin, V. Yu. Davydov, I. N. Goncharuk, A. N. Smirnov, A. E. Nikolaev, M. V. Baidakova, J. Aderhold, J. Graul, J. Stemmer, and O. Semchinova	
Extension of the collision-time tensor to the case of inelastic scattering mechanisms: Application to GaAs and GaN	2536
Jean-Louis Farvacque	
Semiconductors II: surfaces, interfaces, microstructures, and related topics	
Domain wall formation at the $c(2 \times 2)-(2 \times 1)$ phase transition of the CdTe(001) surface	2542
H. Neureiter, S. Tatarenko, S. Spranger, and M. Sokolowski	
Kinetics of dimer-adatom–stacking-fault reconstruction on laser-quenched Si(111) surfaces	2546
K. Shimada, T. Ishimaru, T. Watanabe, T. Yamawaki, M. Osuka, T. Hoshino, and I. Ohdomari	
Screened-exchange LDA methods for films and superlattices with applications to the Si(100) 2×1 surface and InAs/InSb superlattices	2552
R. Asahi, W. Mannstadt, and A. J. Freeman	
Strain and crystallographic orientation effects on the valence subbands of wurtzite quantum wells	2562
Francisco Mireles and Sergio E. Ulloa	
Multiple-spin exchange in a two-dimensional Wigner crystal	2573
Masafumi Katano and D. S. Hirashima	
Spin interactions and switching in vertically tunnel-coupled quantum dots	2581
Guido Burkard, Georg Seelig, and Daniel Loss	
Coulomb effects on the quantum cyclotron resonance from a two-dimensional electron liquid with extremely narrow Landau levels	2593
Yu. P. Monarkha, E. Teske, and P. Wyder	
Laterally coupled few-electron quantum dots	2605
Andreas Wensauer, Oliver Steffens, Michael Suhrke, and Ulrich Rössler	

Pseudopotential calculations of electron and hole addition spectra of InAs, InP, and Si quantum dots	2614
Alberto Franceschetti and Alex Zunger	
Temperature dependence of the Aharonov-Bohm oscillations and the energy spectrum in a single-mode ballistic ring	2624
M. Cassé, Z. D. Kvon, G. M. Gusev, E. B. Olshanetskii, L. V. Litvin, A. V. Plotnikov, D. K. Maude, and J. C. Portal	
Photon-assisted Stückelberg-like oscillations in a double quantum dot	2630
O. Speer, M. E. Garcia, and K. H. Bennemann	
Electron-spin polarization in magnetically modulated quantum structures	2635
Yong Guo, Bing-Lin Gu, Zhong Zeng, Jing-Zhi Yu, and Yoshiyuki Kawazoe	
Quasiparticle properties of quantum Hall ferromagnets	2640
Marcus Kasner, J. J. Palacios, and A. H. MacDonald	
Nonlinear acoustoelectric transport in a two-dimensional electron system	2659
A. O. Govorov, A. V. Kalameitsev, M. Rotter, A. Wixforth, J. P. Kotthaus, K.-H. Hoffmann, and N. Botkin	
Photoconductivity in CdSe quantum dot solids	2669
C. A. Leatherdale, C. R. Kagan, N. Y. Morgan, S. A. Empedocles, M. A. Kastner, and M. G. Bawendi	
Origin of optical anisotropies of nonpolar GaN surfaces	2681
Cecilia Noguez	
Quantum-kinetic dephasing in resonantly excited semiconductor quantum wells	2686
B. Mieck, H. Haug, W. A. Hügel, M. F. Heinrich, and M. Wegener	
Spin coherence and formation dynamics of charged excitons in CdTe/Cd _{1-x-y} Mg _x Zn _y Te quantum wells	2696
E. Vanelle, M. Paillard, X. Marie, T. Amand, P. Gilliot, D. Brinkmann, R. Lévy, J. Cibert, and S. Tatarenko	
Quantum theory of phonon-assisted exciton formation and luminescence in semiconductor quantum wells	2706
A. Thränhardt, S. Kuckenburg, A. Knorr, T. Meier, and S. W. Koch	
Analysis of a special model for a grating coupler	2721
W. L. Schaich	
Optical properties of GaSb/Al _{0.4} Ga _{0.6} Sb multiple quantum wells	2731
C. Bottazzi, A. Parisini, L. Tarricone, R. Magnanini, and A. Baraldi	
Carrier capture and relaxation in Stranski-Krastanow In _x Ga _{1-x} As/GaAs(311)B quantum dots	2737
C. Lobo, N. Perret, D. Morris, J. Zou, D. J. H. Cockayne, M. B. Johnston, M. Gal, and R. Leon	
Magnetophonon resonance in photoluminescence excitation spectra of magnetoexcitons in GaAs/Al _{0.3} Ga _{0.7} As superlattice	2743
S. Dickmann, A. I. Tartakovskii, V. B. Timofeev, V. M. Zhilin, J. Zeman, G. Martinez, and J. M. Hvam	
Molecular-dynamics simulations of nanoscale surface modification of Si(111) via local excitation	2751
Magnus Hedström and Hai-Ping Cheng	
Hydrodynamics beyond local equilibrium: Application to electron gas	2759
I. V. Tokatly and O. Pankratov	
Internal transitions of confined neutral magnetoexcitons in GaAs/Al _x Ga _{1-x} As quantum wells	2773
H. A. Nickel, G. Kioseoglou, T. Yeo, H. D. Cheong, A. Petrou, B. D. McCombe, D. Broido, K. K. Bajaj, and R. A. Lewis	
Diffusion and transport coefficients in synthetic opals	2780
J. O. Sofo and G. D. Mahan	
Microscopic derivation of transport coefficients and boundary conditions in discrete drift-diffusion models of weakly coupled superlattices	2786
L. L. Bonilla, G. Platero, and D. Sánchez	

Surface physics, low-dimensional systems, and related topics

Simulation of scanning tunneling spectroscopy of supported carbon nanotubes	2797
Géza I. Márk, László P. Biró, József Gyulai, Paul A. Thiry, Amand A. Lucas, and Philippe Lambin	
Solitons in carbon nanotubes	2806
Claudio Chamon	
Intergranular segregation and ordering effect: A mixed Monte Carlo mean-field approach	2813
Jérôme Creuze, Fabienne Berthier, Robert Tétot, and Bernard Legrand	
Deposition of Au _N clusters on Au(111) surfaces. I. Atomic-scale modeling	2825
Q. Hou, M. Hou, L. Bardotti, B. Prével, P. Mélinon, and A. Perez	
Deposition of Au _N clusters on Au(111) surfaces. II. Experimental results and comparison with simulations	2835
L. Bardotti, B. Prével, P. Mélinon, A. Perez, Q. Hou, and M. Hou	
Thin films of Co on Pt(111): Strain relaxation and growth	2843
E. Lundgren, B. Stanka, M. Schmid, and P. Varga	
Phase transitions in the adsorption system Li/Mo(112)	2852
A. Fedorus, D. Kolthoff, V. Koval, I. Lyuksyutov, A. G. Naumovets, and H. Pfnür	
Interpreting STM images of the MnCu/Cu(100) surface alloy	2862
D. Wortmann, S. Heinze, G. Bihlmayer, and S. Blügel	
Modeling of metal thin film growth: Linking angstrom-scale molecular dynamics results to micron-scale film topographies	2869
U. Hansen, S. Rodgers, and K. F. Jensen	
Nonmonotonic roughness evolution in unstable growth	2879
Claudio Castellano and Joachim Krug	
Submonolayer epitaxy with impurities: Kinetic Monte Carlo simulations and rate-equation analysis	2889
Miroslav Kotrla, Joachim Krug, and Pavel Šmilauer	
Density-functional study of bulk and surface properties of titanium nitride using different exchange-correlation functionals	2899
M. Marlo and V. Milman	
Coherent lattice vibration of interlayer shearing mode of graphite	2908
Tomobumi Mishina, Kazuki Nitta, and Yasuaki Masumoto	
Surface color centers on epitaxial NaCl films	2912
V. Zielasek, T. Hildebrandt, and M. Henzler	
Molecular-dynamics simulation of thermal stress at the (100) diamond/substrate interface:	
Effect of film continuity	2920
Irina Rosenblum, Joan Adler, Simon Brandon, and Alon Hoffman	
Critical cluster size of metallic Cr and Mo nanoclusters	2937
S. H. Huh, H. K. Kim, J. W. Park, and G. H. Lee	
Evidence of $c(2 \times 2)$ antiferromagnetic order of Mn in an ideal monolayer on Ag(001)	2944
P. Schieffer, C. Krembel, M.-C. Hanf, G. Gewinner, and Y. Gauthier	

ERRATA

Erratum: Cohesion and conductance of disordered metallic point contacts [Phys. Rev. B 60 , 5000 (1999)]	2956
J. Bürki, C. A. Stafford, X. Zotos, and D. Baeriswyl	

Cumulative Author Index	2957
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